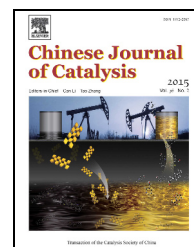


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## Article

# A first principles study of the energetics and core level shifts of anion-doped TiO<sub>2</sub> photocatalysts



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## ABSTRACT

We present a comprehensive and improved density functional theory (DFT) calculation of anion-doped (anion = B, C, N, F, P, S) anatase and rutile TiO<sub>2</sub>. The first part is a first principles calculation of the core level shifts (CLS) for various anion dopants in both anatase and rutile TiO<sub>2</sub>. The CLS results revealed that interstitial N had a higher N 1s binding energy than substitutional N, which agreed well with experimental results. The calculation also showed that for B-, C-, S-, and P-doped TiO<sub>2</sub>, the interstitial dopant had an energy that is higher than that of a substitutional dopant, which is similar to N-doped TiO<sub>2</sub>. However, for F-doped TiO<sub>2</sub>, the energy of the substitutional dopant is higher, and this is irrespective of the TiO<sub>2</sub> crystallography. We also calculated the enthalpy of doping and found that the substitutional dopant had a higher enthalpy than the interstitial dopant. The results revealed that substitutional doping required severe experimental conditions, whereas interstitial doping only requires modest wet chemistry conditions.

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## 1. Introduction

In 1972, Fujishima et al. [1] discovered photoelectron chemical splitting of water on TiO<sub>2</sub> electrodes, which led to extensive investigations of TiO<sub>2</sub> as a photocatalyst. TiO<sub>2</sub> is one of the most promising photocatalysts for the photocatalytic degradation of organic pollutants and photocatalytic dissociation of water. However, the wide bandgap of anatase TiO<sub>2</sub> (3.2 eV) limits its photocatalytic applications to the ultraviolet (UV) light range. Meanwhile, the relatively high rate of electron-hole recombination results in a low quantum yield and poor efficiency in promoting photocatalytic reactions. These fundamental problems prevent the use of anatase TiO<sub>2</sub> in practical applications. Therefore, one of the endeavours to improve the performance of TiO<sub>2</sub> is to increase its optical efficiency by

shifting the onset of its response from the UV to the visible region [2–5]. One strategy is to dope TiO<sub>2</sub> with an anion such as B, C, N, F, P, or S to decrease its band gap.

Compared to other anion dopants, N has been proven to be one of the most efficient for visible light-responsive TiO<sub>2</sub> photocatalysts [3,5], and this system has been studied extensively by experiments. Various methods have been developed to prepare N-doped TiO<sub>2</sub> photocatalysts (powders and films), such as sputtering [3,6–8], ion implantation [9–12], controlled hydrolysis or sol-gel [13–24], and chemical treatment of TiO<sub>2</sub> [3,9,12,25–30]. Although these N-doped TiO<sub>2</sub> photocatalysts are visible light-active, there are debates on their structures, particularly on the location of the active N atoms and the origin of the bandgap narrowing in N-doped TiO<sub>2</sub>. Asahi et al. [3] indicated that N atoms substituted for O atoms in N-doped TiO<sub>2</sub>

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and the decrease of the bandgap originated from the mixing of the O 2*p* and substitutional N 2*p* states. Diwald et al. [9] concluded that N atoms can also be located at interstitial sites in N-doped TiO<sub>2</sub>, and they further confirmed that this nitrogen state was responsible for the observed shift of the photochemical threshold of rutile TiO<sub>2</sub>(110) down to 2.4 eV. Irie et al. [12] proposed that the isolated narrow N 2*p* band formed by substitutional N in N-doped TiO<sub>2</sub> above the O 2*p* valence band was responsible for the visible light response. Serpone [31] argued that the visible light activation of N-doped TiO<sub>2</sub> was due to defects associated with oxygen vacancies that gave rise to color centers. Recently, Livraghi et al. [19] investigated N-doped TiO<sub>2</sub> by a combined experimental and theoretical approach and suggested that N<sub>b</sub>• centers (single atom nitrogen in the bulk of TiO<sub>2</sub>) played an essential role in the absorption of visible light, in the promotion of electrons to the conduction band, and in photoinduced electron transfer to reducible adsorbates. So far, the most common technique to detect doped N atoms in TiO<sub>2</sub> is by X-ray photoelectron spectroscopy (XPS). N 1*s* XPS peaks with different binding energies have been reported for N-doped TiO<sub>2</sub> prepared by different methods, but their assignments are still not conclusive. Compared with N in TiN, the N 1*s* XPS feature with its binding energy at 397.0 eV is generally assigned to N<sup>2-</sup> anions that are substituted for O in the TiO<sub>2</sub> lattice. However, Chen et al. [32] attributed a N 1*s* peak with its binding energy at 401.3 eV to substitutional N in O–Ti–N. Diwald et al. [9] prepared N-doped rutile TiO<sub>2</sub>(110) by heating in NH<sub>3</sub> and observed two N 1*s* peaks with binding energy at 396.7 and 399.6 eV, which were assigned to substitutional and interstitial N atoms, respectively. Rodriguez et al. [33] reported the N 1*s* binding energy of atomic N adsorbed on rutile TiO<sub>2</sub>(110) to be 399.0 eV. Therefore, a clear understanding of the structures of N-doped TiO<sub>2</sub> photocatalysts is of great importance. Recently, other nonmetal-doped TiO<sub>2</sub> with dopants like B, C, or F have also received growing interest from both experiments and theoretical calculations [19,34–46].

In theoretical studies, Di Valentin et al. [19,36,41–46] have published a number of papers on nonmetal-doping of TiO<sub>2</sub>. In their work, they performed a lot of electronic state analysis on the localized states formed in the band gap of TiO<sub>2</sub>. In addition, they also performed core level shift (CLS) studies for different doping positions. Their CLS value of different N locations in N-doped anatase TiO<sub>2</sub> is 1.6 eV with the initial state approximation. They also showed in their calculations that there existed a difference of 2.6 eV between interstitial B and substitutional B with initial state relaxation effects considered [36]. However, their CLS results may be more convincing if they had considered final state relaxation in their calculations.

The locations of anions and thermodynamic stability are two aspects of most concern to experimentalists. Therefore, in this work, we comprehensively studied the CLS and thermodynamic stability for different doping anions (B, C, N, F, P, and S), different doping types (substitutional and interstitial), and different TiO<sub>2</sub> phases (rutile and anatase). In the energetics calculations, especially with N-doping, we have considered the difference between the PBE functional and hybrid HSE06 functional.

In the first part of the work, we determined the optimized structures of the anion-doped TiO<sub>2</sub>. Then in the second part, we employed standard and hybrid density function theory (DFT) calculations for an energetics study of anion-doped TiO<sub>2</sub>. We study the thermodynamics in an effort to find the fundamental reason for the different N-doped TiO<sub>2</sub> types identified by the different preparation methods. Although there are less experimental studies than on N-doped TiO<sub>2</sub>, some conclusions for the systems of B-, C-, F-, P-, or S-doped TiO<sub>2</sub> can be given. In the last part, DFT calculations with final state relaxation effects included were employed to provide comprehensive and precise insight into the CLS results of anion-doped TiO<sub>2</sub>. In this part, we studied different doping locations, anions, and TiO<sub>2</sub> phases. We hope these CLS calculations help distinguish the close peaks in the XPS spectra.

## 2. Theoretical approaches and computational details

Spin-polarized total energy calculations were performed based on the all-electron projected augmented wave (PAW) method and DFT within the generalized gradient approximation (GGA-PBE) using a HSE06 hybrid functional as implemented in the Vienna Ab Initio Simulation 5.2 Package (VASP) [47–54]. A cutoff of 400 eV was used for the plane wave expansion. Throughout the present work, optimized equilibrium lattice constants (anatase TiO<sub>2</sub>:  $a = 3.82$  Å,  $c = 9.62$  Å; rutile TiO<sub>2</sub>:  $a = 4.66$  Å,  $c = 2.97$  Å), which agreed well with previous calculations [45] and experiments (anatase TiO<sub>2</sub>:  $a = 3.78$  Å,  $c = 9.52$  Å; rutile TiO<sub>2</sub>:  $a = 4.59$  Å,  $c = 2.96$  Å) [5], were used unless otherwise stated. To study anion doping in the TiO<sub>2</sub> bulk, one anion atom was included in the anatase (3×3×1) supercell with dimensions of 11.46 Å × 11.46 Å × 9.62 Å and rutile (2×2×3) supercell with dimension of 9.32 Å × 9.32 Å × 8.91 Å, which corresponded to the doping concentration of 1.4% and 2.1%, respectively. For the Brillouin zone integration, we employed a Monkhorst-Pack (2×2×4) and (4×4×4)  $\Gamma$ -centered k-point grid for the anatase (3×3×1) and rutile (2×2×3) supercell. All the ions in the super cell were relaxed until the residual force on each ion was less than 0.01 eV/Å.

CLS were calculated as the energy difference between the core level binding energy of the atom of interest ( $E_{\text{cl}}^{\text{cl}}$ ) and a reference atom ( $E_{\text{cl}}^{\text{ref}}$ ), i.e.,  $\text{CLS} = E_{\text{cl}}^{\text{cl}} - E_{\text{cl}}^{\text{ref}}$ . The core level binding energy ( $E_{\text{cl}}$ ) can be calculated in both the initial state and final state approximations. In the initial state approximation,  $E_{\text{cl}}$  is the negative eigenvalue ( $-\varepsilon_{\text{c}}$ ) of the orbital from which the core electron has been excited, where  $E_{\text{cl}} = -\varepsilon_{\text{c}}$  and  $\varepsilon_{\text{c}}$  refers to the Fermi level for the solid and vacuum for the gas. In the final state approximation,  $E_{\text{cl}}$  was calculated by the total energy difference between the two configurations, which were an excited configuration in which an electron was removed from a particular core state,  $E_{\text{tot}}(n_{\text{c}} - 1)$  and the ground state configuration,  $E_{\text{tot}}(n_{\text{c}})$ . Thus,  $E_{\text{cl}} = E_{\text{tot}}(n_{\text{c}} - 1) - E_{\text{tot}}(n_{\text{c}})$ , in which the core-hole was assumed to remain localized in the excited atom.

In this work, for the final state calculation, a core electron was removed from the core by generating the corresponding core excited ionic PAW potential in the calculation, and the remaining core states were relaxed in the self-consistent calcu-

lation.

### 3. Results and discussion

#### 3.1. Optimized structures of anion-doped TiO<sub>2</sub>

In this work both anion substitution and interstitial doping were considered. As all the O atoms are in the same position, there is only one possibility for the anion substitution location. However, for the interstitial-doped anion, there are three possible equivalent positions in anatase TiO<sub>2</sub> and two possible positions in rutile TiO<sub>2</sub>, as shown in Fig. 1. The optimized coordinate of the interstitial N atoms in each structure and the total energy of the optimized structure are summarized in Fig. 2. For interstitial N-doped anatase, the A3 type exhibited the lowest total energy, in agreement with the previous result [45]. For interstitial N-doped rutile, the R2 type is more stable. Therefore, the a<sub>2</sub> type and the R2 type were chosen as the models for the further theoretical investigations of interstitial N-doped anatase and rutile, respectively. Similar work was done on the other anion-doped TiO<sub>2</sub>. The results are listed in Table 1. It can be seen that the location depended on the size of the atomic radius. Larger anions prefer the larger interspace. Compared with bulk TiO<sub>2</sub>, the atoms surrounding the doped anion were slightly relaxed in the anion-doped TiO<sub>2</sub>.

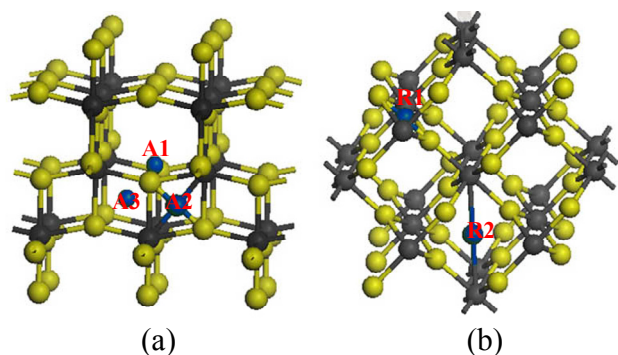


Fig. 1. Different interstitial sites in anatase TiO<sub>2</sub> (a) and rutile TiO<sub>2</sub> (b).

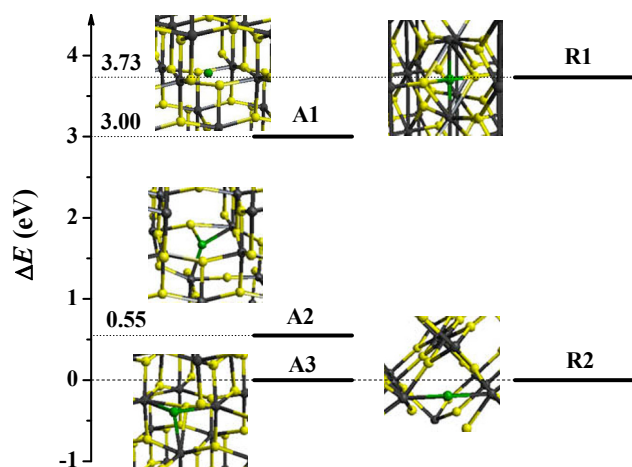


Fig. 2. Energy difference in N-doped TiO<sub>2</sub> after crystal relaxation.

Table 1

Interstitial doping anion sites used in the calculations and Pauli electronegativity of the atoms.

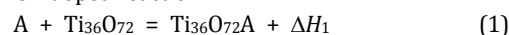
Atom	Anatase TiO <sub>2</sub>	Rutile TiO <sub>2</sub>	Atomic radius (pm) [55]	Pauli electronegativity [56]
B	A1 <sup>a</sup>	R2	85	2.04
C	A2	R2	70	2.55
N	A2	R2	65	3.04
F	A2	R2	50	3.98
P	A1	R2	100	2.19
S	A2	R2	100	2.58
O			60	3.44
Ti			140	1.54

<sup>a</sup>Location of the anion (from Fig. 1).

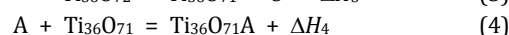
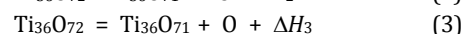
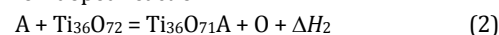
#### 3.2. Energetics study of anion-doped TiO<sub>2</sub>

To compare the reaction enthalpy of the reactions producing interstitial and substitutional anion-doped TiO<sub>2</sub>, we considered the reaction, which is that of one anion with TiO<sub>2</sub> to produce anion-doped TiO<sub>2</sub>. The source of the anion atom would offset in the enthalpy comparison of two types of anion-doped TiO<sub>2</sub>, thus for interstitial doping, there is only one process in which anions get into the favorable interstitial space of the TiO<sub>2</sub> lattice. However, for substitutional doping, there are three processes in which O atoms first are removed from the TiO<sub>2</sub> lattice leading to the formation of oxygen vacancies, and anions fill these vacancies at the same time. As the sources of the anion and final form of the O atom are not unique, the doping reaction can be described as the following for anatase TiO<sub>2</sub> on the basis of the structural model:

Interstitial anion-doped reaction

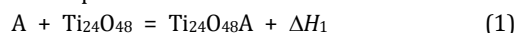


Substituting anion-doped reaction

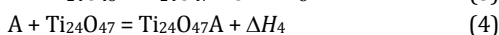
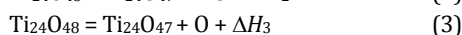
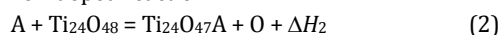


For rutile TiO<sub>2</sub>, the doping reaction equations are the following:

Interstitial anion-doped reaction



Substituting anion-doped reaction



$\Delta H$  was calculated by the equation  $\Delta H = \Sigma E(\text{products}) - \Sigma E(\text{reactants})$ , in which  $E$  represents the total energy.

Reaction (2) is not the same as reaction (1), which has stable products, so the final form of the O atom should be included in reaction (2). In other words, there should be an additional enthalpy  $\Delta H_5$  added to  $\Delta H_2$  in the case of the comparison with  $\Delta H_1$ , where  $\Delta H_5$  is the enthalpy of the process where the O atom changed into the final form, which is determined by the particular reaction route.

To identify the error from using different methods, both the PBE functional and HSE06 hybrid functional were used for N-doped TiO<sub>2</sub>, as listed in Table 2. It can be seen that the ener-

**Table 2**

Energetics comparison of N-doped TiO<sub>2</sub> obtained with the PBE and hybrid HSE06 functionals.

TiO <sub>2</sub>	PBE/eV				HSE06/eV			
	$\Delta H_1$	$\Delta H_2$	$\Delta H_3$	$\Delta H_4$	$\Delta H_1$	$\Delta H_2$	$\Delta H_3$	$\Delta H_4$
Anatase TiO <sub>2</sub> (3×3×1)	-0.82	3.11	7.11	4.00	-0.08	3.73	7.26	3.53
Rutile TiO <sub>2</sub> (2×2×3)	0.94	2.90	7.20	4.30	2.22	3.30	5.86	2.56

getics did not exhibit a strong dependence on the functional used in this study. Because the HSE06 functional is more time consuming than the PBE, the other anion-doped TiO<sub>2</sub> energetics calculations were performed with the standard PBE functional. The results are shown in Fig. 3 and Fig. 4. As the anions do not appear in reaction (3), the values of  $\Delta H_3$  do not change for the same system, which are 7.11 and 7.20 eV for anatase and rutile TiO<sub>2</sub>, respectively. The substitutional anion-doped reaction was strongly endothermic for both anatase and rutile TiO<sub>2</sub>, but the interstitial anion-doped reaction can be exothermic or slightly endothermic. There existed a large energy barrier for substitutional N-doped TiO<sub>2</sub> for both anatase and rutile TiO<sub>2</sub>, and the value of  $\Delta H_3$  was a quite positive number compared with  $\Delta H_1$ . The larger energy value can explain why substitutional N-doped TiO<sub>2</sub> usually requires severe reaction conditions, such as ion implantation and sputtering, or nitridizing TiO<sub>2</sub> in N<sub>2</sub> or NH<sub>3</sub> at high temperatures, whereas interstitial N-doped TiO<sub>2</sub> can be prepared via mild wet chemistry reactions. However, this comparison cannot provide insights into

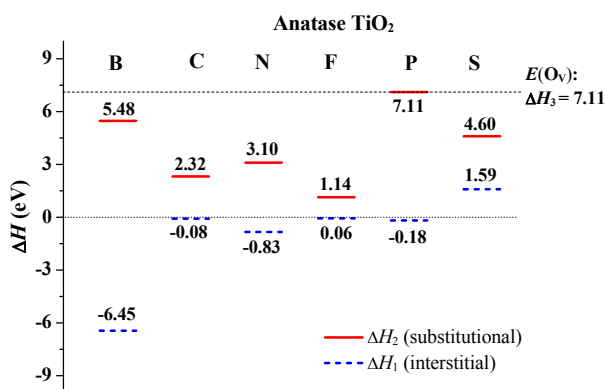


Fig. 3. Comparison of enthalpy change for anion-doped anatase TiO<sub>2</sub>.

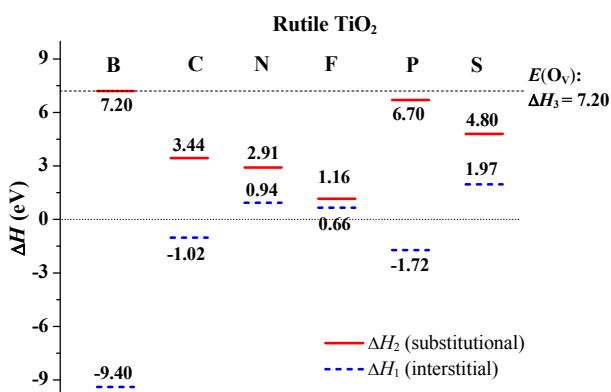


Fig. 4. Comparison of enthalpy change for anion-doped rutile TiO<sub>2</sub>.

which product is formed at a given severe reaction condition, and the process of how the O atom changed into its final form therefore should be taken into account. In the following part, we used O<sub>2</sub> as the final form of the O atom to address this issue. The total energy of O<sub>2</sub> was also included in our work, with the energy of a O<sub>2</sub>  $E(O_2) = -9.857$  eV and a single O atom  $E(O) = -1.90$  eV. Thus another reaction is  $O = 0.5O_2 + \Delta H_5$ , with the value of  $\Delta H_5 = -3.02$  eV.  $\Delta H_5$  should be added to  $\Delta H_2$ , and then compared with  $\Delta H_1$ . Fig. 3 shows that for B- or P-doped TiO<sub>2</sub>, interstitial doping was still more favorable than substitutional doping, which means that under severe conditions and with the final form of O, interstitial B- or P-doped TiO<sub>2</sub> is still more easily prepared than substitutional B- or P-doped TiO<sub>2</sub>. N-, C-, or S-doped TiO<sub>2</sub> tended to have a similar enthalpy change, while F-doped TiO<sub>2</sub> showed the reversed trend. As the value of  $\Delta H_5$  depended on the final form of the O atoms, different preparation solutions can lead to different mixtures of interstitial and substitutional doped products. In experimental preparations when severe conditions were provided for N doping of TiO<sub>2</sub>, there were always two N 1s peaks in the XPS spectra [3,9,12] whereas when the conditions used were mild, there was only one peak [23,24]. From the energetics study, we can identify that with a mild environment, only interstitial N-doped TiO<sub>2</sub> is produced, and both types of N-doped TiO<sub>2</sub> exist when severe conditions are used.

### 3.3. CLS study of anion-doped TiO<sub>2</sub>

#### 3.3.1. CLS study of interstitial and substitutional doping

For the core level of the anion doped into TiO<sub>2</sub>, the two different types of doping: substitutional and interstitial doping showed two close peaks in the XPS spectra. These two peaks cannot be distinguished just by the experimental data, and the CLS by a DFT study can be used to identify these close peaks. We have found that the most stable location is the interstitial site. Then, we performed a CLS study of the two different doping types with standard DFT for B-, C-, N-, F-, P-, and S-doped TiO<sub>2</sub>. The results are shown in Fig. 5 and Table 3.

From Fig. 5, we can see that for B-, C-, N-, F-, P-, and S-doped TiO<sub>2</sub>, there exists a clear difference between substitutional and interstitial doping. Most interstitial anion dopants type had a higher core level binding energy than that of the substitutional dopant, except for F-doped TiO<sub>2</sub>. For N-doped TiO<sub>2</sub>, it was

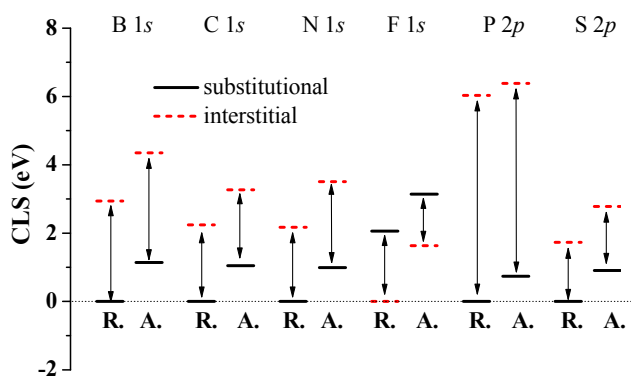


Fig. 5. CLS results of anion-doped anatase TiO<sub>2</sub> and rutile TiO<sub>2</sub>.

**Table 3**

Calculated B, C, N, and F 1s and P and S 2p CLSs in anion-doped anatase and rutile TiO<sub>2</sub>. The energy references are substitutional rutile (2×2×3) for B, C, N, P, and S and interstitial rutile (2×2×3) for F.

TiO <sub>2</sub>		CLS (eV)					
		B 1s	C 1s	N 1s	P 2p	S 2p	F 1s
Anatase TiO <sub>2</sub> (3×3×1)	interstitial	4.26	3.10	3.38	6.41	2.79	1.47
	substitutional	1.05	0.88	0.86	0.77	0.92	2.98
Rutile TiO <sub>2</sub> (2×2×3)	interstitial	2.94	2.24	2.17	6.03	1.73	0
	substitutional	0	0	0	0	0	2.06

found that the N 1s core level binding energy of the interstitial N species was higher than that of the substitutional N species for both N-doped anatase TiO<sub>2</sub> and rutile TiO<sub>2</sub>. The CLSs were 2.52 and 2.17 eV for N-doped anatase and rutile TiO<sub>2</sub>, respectively. Experimentally, N 1s XPS peaks with different binding energies have been observed by XPS for N-doped TiO<sub>2</sub> prepared by different methods. Asahi et al. [3] assigned the N 1s peak with a binding energy at 396 eV to substitutional N in N-doped anatase TiO<sub>2</sub> prepared by sputtering a TiO<sub>2</sub> target in a N<sub>2</sub> atmosphere. Chen et al. [32] attributed the N 1s peak with a binding energy at 401.3 eV to substitutional N in N-doped anatase TiO<sub>2</sub> prepared by treating TiO<sub>2</sub> with an excess of triethylamine. Diwald et al. [9] prepared N-doped rutile TiO<sub>2</sub>(110) by heating in NH<sub>3</sub> and observed two N 1s peaks with binding energies at 396.7 and 399.6 eV, which were assigned to substitutional and interstitial N atoms, respectively. Fang et al. [23] assigned the N 1s peak with a binding energy at 399.6 eV to interstitial N in N-doped anatase TiO<sub>2</sub> prepared by a wet chemistry method. Comparing the N in TiN with a N 1s binding energy at 397 eV [57], it has been generally accepted that the N 1s peak with a binding energy at 396–397 eV is from substitutional N in N-doped TiO<sub>2</sub>. However, the evidence for the assignment of the N 1s peak with a binding energy at 399.6 eV to interstitial N in N-doped TiO<sub>2</sub> is lacking. Our theoretical calculations fully support the assignments: substitutional N in N-doped TiO<sub>2</sub> exhibits N 1s binding energy between 396 and 397 eV and interstitial N in N-doped TiO<sub>2</sub> exhibits the N 1s binding energy at 399.6 eV. Our results also suggested the assignment of the N 1s peak with a binding energy at 401.3 eV to substitutional N in N-doped anatase TiO<sub>2</sub> already made by Chen et al. [32]. Meanwhile, on basis of the calculated enthalpy for the N-doping reaction, it is also reasonable to conclude that treating TiO<sub>2</sub> with an excess of triethylamine that was employed by Chen et al. [32] should not be able to form the substitutional N species.

### 3.3.2. CLS study of the different anions

We summarized the CLS results of different anion-doped TiO<sub>2</sub> in Fig. 5 and Table 3. Our calculations showed that the  $E_{CLS}$  value of anion-doped TiO<sub>2</sub> was positive except for F-doped TiO<sub>2</sub>. This means that in the XPS spectra of anion-doped TiO<sub>2</sub>, the interstitial doping peak is located higher than that of substitutional doping. The CLS results (Fig. 5) showed that the F atom gave a reverse trend compared with other anions. This can be understood through the Pauli electronegativity of these atoms [56] (Table 1). The electronegativity value of O is larger than those of B, C, N, P, and S, while smaller than that of F. After an O

atom is substituted by an anion, the Ti atoms are closer than with the O atoms, while for interstitial doping, the O atoms are closer than the anion. The difference in the structure between substitutional and interstitial doping is that more nearby O atoms surround the anion in interstitial doping. According to the sequence of the electronegativity [56], there is more electron transfer from O to F in interstitial doping than substitutional doping; while for B-, C-, N-, P-, or S-doping of TiO<sub>2</sub>, there is the reverse electron transfer direction, and substitutional doping gets more electrons than interstitial doping. As we know, when more electrons are moved away, the binding energy would be larger. Thus, the B, C, N, P, and S atoms in interstitial doping sites have a higher core level energy than those in substitutional doping sites; and F-doped TiO<sub>2</sub> has a reverse trend. When this conclusion is applied to the XPS spectra, for B-, C-, N-, P-, and S-doped TiO<sub>2</sub>, the peak from interstitial doping is higher than that from substitutional doping; and for F-doped TiO<sub>2</sub>, that from substitutional doping is higher than interstitial doping.

### 3.3.3. CLS study between the different phases of TiO<sub>2</sub>

We have studied the anion CLS for both the rutile and anatase, as shown in Fig. 5 and Table 3. The results revealed that both anatase and rutile showed the same sequence of the substitutional and interstitial dopant peaks. However, for the same dopant, the core level binding energy of the anion in anatase is a little higher than that in rutile. The probable reason may be that the density of rutile is larger than that of anatase. As the distance between two neighboring atoms is less, the interaction between Ti and the anion is stronger, thus, the anion can accept more electrons in rutile than anatase. As discussed above, when more electrons are lost, the core level binding energy is higher. Therefore, the binding energy of the anion in anatase is higher than in rutile.

## 4. Conclusions

We have performed comprehensive and improved DFT calculations of anion-doped anatase and rutile TiO<sub>2</sub>. The N 1s core level binding energy calculations suggested that interstitial N species exhibit a higher N 1s binding energy than substitutional N species in N-doped TiO<sub>2</sub>. The calculated core level shift between interstitial and substitutional N species agreed well with experimental data, which strongly supports the assignments of the experimental XPS results. Our calculations provide a fundamental understanding of N-doped TiO<sub>2</sub> photocatalysts. We also performed CLS calculations for B-, C-, F-, P-, and S-doped TiO<sub>2</sub> and show that in F-doped TiO<sub>2</sub>, the interstitial dopant peak is lower than that of the substitutional dopant. However, for B-, C-, N-, P-, and S-doped TiO<sub>2</sub>, the peak of the interstitial dopant is higher than that of the substitutional dopant. The enthalpy calculations demonstrated that the substitutional anion-doped reaction is strongly exothermic for both anatase and rutile TiO<sub>2</sub> due to the intermediate production of oxygen vacancies, whereas the interstitial anion-doped reaction is modestly endothermic. Our calculations suggested that for B, C, N, F, P, and S anion-doped TiO<sub>2</sub>, severe experimental conditions are re-

quired for substitutional doping, while for interstitial doping, wet chemistry methods would be enough.

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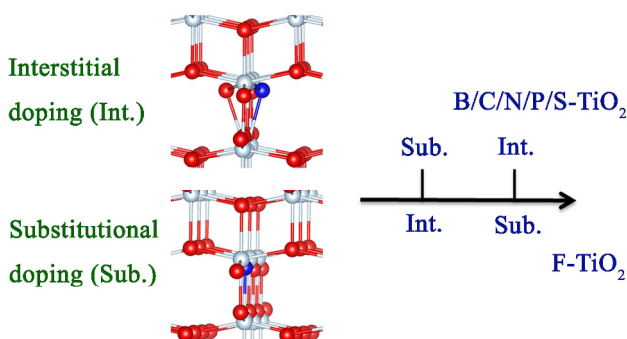
## Graphical Abstract

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### A first principles study of the energetics and core level shifts of anion-doped TiO<sub>2</sub> photocatalysts

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Core level shifts in B-, C-, N-, S-, or P-doped TiO<sub>2</sub> are such that the energy of an interstitial dopant is higher than that of a substitutional dopant, but for F-doped TiO<sub>2</sub>, the energy of the substitutional dopant is higher.



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